

TOSHIBA LED LAMP InGaAlP RED LIGHT EMISSION

TLSH180P

PANEL CIRCUIT INDICATOR

- 5 mm DIAMETER (T1-3 / 4)
- InGaAlP RED LED
- All Plastic Mold Type.
- Colorless Clear Lens
- Low Drive Current, High Intensity Red Light Emission
Recommended Forward Current : $I_F = 1 \sim 20$ mA (DC)
- All Plastic Molded Lens, Provides an Excellent ON-OFF Contrast Ratio.
- Fast Response Time, Capable of Pulse Operation.
- High Power Luminous Intensity
- Without stand-offs
- APPLICATIONS : Suitable for Outdoor Message Signboard,
Safety equipment.

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Forward Current (DC)	I_F	50	mA
Reverse Voltage	V_R	4	V
Power Dissipation	P_D	125	mW
Operating Temperature Range	T_{opr}	$-30 \sim 85$	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-40 \sim 120$	$^\circ\text{C}$

ELECTRICAL AND OPTICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Forward Voltage	V_F	$I_F = 20$ mA	—	2.1	2.5	V
Reverse Current	I_R	$V_R = 4$ V	—	—	50	μA
Luminous Intensity	I_V	$I_F = 20$ mA (Note)	2720	10000	—	mcd
			4760	—	23000	
Peak Emission Wavelength	λ_p	$I_F = 20$ mA	—	623	—	nm
Spectral Line Half Width	$\Delta\lambda$	$I_F = 20$ mA	—	15	—	nm
Dominant Wavelength	λ_d	$I_F = 20$ mA	—	613	—	nm

(Note) : Lamps are classified into the following ranks according to their luminous intensity.

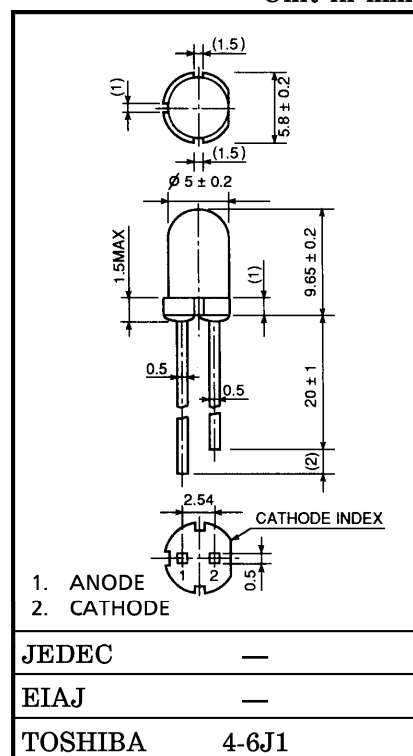
Measurement tolerance for each limit is $\pm 15\%$.

U : 3200-6400 mcd, V : 5600-11200 mcd, W : 8500-23000 mcd.

961001EAC2

- TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.
- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

Unit in mm



Weight : 0.31 g

PRECAUTION

Please be careful of the followings

- Soldering temperature : 260°C max Soldering time : 3 s max
(Soldering portion of lead : up to 2 mm from the body of the device)
- If the lead is formed, the lead should be formed up to 5 mm from the body of the device without forming stress to the resin. Soldering should be performed after lead forming.
- This visible LED lamp also emits some IR light. If a photodetector is located near the LED lamp, please ensure that it will not be affected by this IR light.

